

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L10	82118	(FET (field adj effect adj transistor))	USPAT	OR	OFF	2009/02/16 20:38
L11	1012	10 same heterojunction	USPAT	OR	OFF	2009/02/16 20:38
L12	238	(AlN (aluminum adj nitride)) with passivat \$4	USPAT	OR	OFF	2009/02/16 20:39
L13	17	11 and 12	USPAT	OR	OFF	2009/02/16 20:39
L20	7	11 same (passivat\$4 with surface)	USPAT	OR	OFF	2009/02/16 21:26

2/ 16/ 2009 9:35:00 PM